O rbital Insulators and O rbital O rder-disorder Induced M etal-Insulator Transition in Transition-M etal O xides

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Abstract

The role of orbital ordering on m etal-insulator transition in transition-m etal oxides is investigated by the cluster self-consistent eld approach in the strong correlation regime. A clear dependence of the insulating gap of single-particle excitation spectra on the orbital order param eter is found. The therm all uctuation drives the orbital order-disorder transition, dim in ishes the gap and leads to the m etal-insulator transition. The unusual tem perature dependence of the orbital polarization in the orbital insulator is also m an ifested in the resonant x-ray scattering intensity.

KEYWORD: Orbital ordering, metal-insulator transition, orbital insulator, resonant X-ray scattering

I. IN TRODUCTION

M etal-insulator transition (M IT) in strongly correlated transition-m etaloxides (TMO) is one of the central problem s in condensed m atter physics, it has attracted extensive attention in recent decades since it has been found that high tem perature superconductivity, colossal m agnetoresistance and m any other phenom ena occur in the vicinity of M IT^{1;2)}. These strongly correlated electronic system s exhibit very com plicated and rich phase diagram s with tem perature, doping, pressure and m agnetic $eld^{3;4}$. In these com pounds, the tem perature induced M IT in V₂O₃ and m anganites is especially interesting, because the M IT tem perature T_M is much smaller than the insulating gap () in transport, for example in V₂O₃, $T_M = 154$ K << = 0.6 eV⁵⁾. Obviously, the therm all uctuation is not the driven force of the M IT. It has recently realized that the orbital degree of freedom and orbital ordering (OO) play in portant roles in the groundstate (G S) properties of these TMO.

The OO was rst proposed to explain the complicated magnetic structures by Kugelet al. ⁶⁾ for K C uF₃ and by C astellani et al. ⁷ for V₂O₃. D ue to the strong correlation between 3d electrons and the large anisotropy of the 3d wavefunctions, the orbital degree of freedom and the OO a ect m any electronic and magnetic properties of these strongly correlated system s ^{4,6} ⁹⁾, and have been extensively studied in colossalm agnetoresistive magnetics, vanadium oxides and m any other TM O [for example, see R ef.10]. Experimentally orbital order-disorder transition is usually accompanied by M II, such as in prototype M II compound V₂O₃, an obvious insulator to m etal transition occurs at $T_M = T_C$ ¹¹⁾, here T_C is the Curie-W eiss tem – perature. It is believed that in V₂O₃, the OO transition (OOT), the M II and the magnetic transition occur simultaneously, i.e. $T_M = T_{OO} = T_C$ ¹²⁾. We also notice that in lightly doped La_{0.68}Sr_{0.12}M nO₃ the ferrom agnetic insulator to ferrom agnetic m etal transiting at T_M is identified as an OOT by Endoh et al¹³, or, $T_M = T_{OO}$, ruling out the signific cant role of cooperative Jahn-Teller (JT) distortion on the GS. The orbital phase transition near the vicinity of M II is also reported in La_{1-x}C a_xM nO₃ (x 0.2)¹⁴. These experiments clearly establish a close relationship between OOT and M II . Theoretically C astellani et al.

rst suggested the correlation between OOT and M II in V_2O_3 ⁷⁾, they proposed that the M II associated with the OO was driven by the variation of the entropy in the presence of long-range m agnetic and orbital orders. K haliullin et al. ¹⁵ attributed this correlation to the form ation of orbital polaron. Nevertheless, it is not well understood theoretically how

the 00 insulator evolves to M IT with lifting tem perature.

In this paper, we demonstrate that the strong orbital correlation in TMO with orbital degenerate 3d electrons leads the GS to be an orbital insulator, and the orbital order-disorder driven MIT. Starting from a twofold-degenerate spin-orbital interacting model, and using the cluster self-consistent eld (cluster-SCF) approach developed recently, we rst determ ine the 00 GS; and then show that the insulating gap of the single-particle spectrum opens as the long-range 00 establishes. With increasing temperature, the therm all uctuation drives 00 T, also the energy gap of the single-particle excitation vanishes at T_{00} , indicating the transition from insulator to metal. The resonant X-ray scattering (RXS) intensity diminishes to zero near the critical temperature T_{00} . The rest of this paper is organized as follows: in Sec.II we describe the elective model H amiltonian of an orbital insulator and the cluster-SCF approach; then we present the magnetic and orbital structures in GS, the T-dependent 00 parameters and the gap of single-particle excitation spectra in Sec.III; the variation of the tem perature and the azim uthal angle dependence of the RSX intensity are given in Sec.IV, and the last section is devoted to the remarks and summary.

II. MODEL HAM ILTON IAN AND METHOD

In many perovskite transition-metaloxides under the octahedral crystalline eld, the vefold degenerate 3d orbits of the transition metal ions split into lower t_{2g} and higher E_g orbits. For claric cation and simplic cation we consider such an ideal cubic TMO system that the $\frac{1}{2g}$ orbits are led and contribute no spin, and the twofold degenerate E_g orbits are occupied by one hole or one electron, corresponding to the electron conguration of 3d in KCuF₃ or 3d⁷ in LaN iO₃. Such a system is spin-1/2 and twofold orbital degenerate, or the orbital pseudospin = 1/2. We denote the two E_g orbits as $jli=je_{g1}i=jd_{3z^2}r^2i$ and $j2i=je_{g2}i=jd_{x^2}y^2i$. The major low-energy physics of the system is described by the twofold-degenerate H ubbard model with strong C oulom b interaction ^{6;7)}. In the second-order perturbation approximation the E_g electrons interact with each other through the low-energy superexchange coupling, which is expressed as:

$$H_{SE} = \begin{pmatrix} X \\ J_{1}\mathbf{s}_{i} & \mathbf{s}_{i} + J_{2}\mathbf{I}_{i}^{1}\mathbf{s}_{i} & \mathbf{s}_{i} + J_{3}\mathbf{I}_{i}^{1}\mathbf{I}_{j_{1}}^{1}\mathbf{s}_{i} & \mathbf{s}_{i} \\ & \stackrel{\text{hiji}_{1}}{\overset{\text{hiji}_{1}}{\overset{\text{h}}{\underset{l}=x_{i}y_{i}z_{i}}} \\ & + J_{4}\mathbf{I}_{i}^{1}\mathbf{I}_{j_{1}}^{1} \end{pmatrix}$$
(2.1)

where the operator $I_1^1 = \cos(2 m_1=3) \frac{z}{1}$ sin $(2 m_1=3) \frac{x}{1}$, the index 1, 1 = x;yor z, denotes the direction of a bond; hiji₁ connects site i and its nearest-neighbor site j along the 1 direction, and $(m_x, m_y, m_z) = (1,2,3)$. ^z and ^x are the Pauli matrix, ^z = $\frac{1}{2}$ represents the orbital polarization in the state jli and ^z = $\frac{1}{2}$ the orbital polarization in the state jli. Thus the polarization degree of the orbit, h i, is called the orbitalization. The constants $J_1; J_2; J_3$ and J_4 are the superexchange interactions, and are read: $J_1 = 8t^2 [U = (U^2 J_H^2) J_H = (U_1^2 J_H^2)]$, $J_2 = 16t^2 [I = (U_1 + J_H) + 1 = (U + J_H)]$, $J_3 = 32t^2 [U_1 = (U_1^2 J_H^2) J_H = (U^2 J_H^2)]$, and $J_4 = 8t^2 [(U_1 + 2J_H) = (U_1^2 J_H^2) + J_H = (U^2 J_H^2)]$, with $U = U_1 + 2J_H$, here 4t is the hopping integral between the jli orbits along the z direction. U and U_1 are the intra- and interorbital C oulomb interactions, and J_H is the Hund's rule coupling. In this paper we adopt t = 0.1 eV and $J_H = 0.9 \text{ eV}$.

Clearly, the fourth term in Eq.(1) is an orbital fustration interaction: while the exchange along the z direction stabilizes the alternating $\beta z^2 r^2 i$ and $jx^2 y^2 i$ conguration, the equivalent coupling along the x or the y directions favors other orbital pair conguration, i.e. $\beta x^2 r^2 i$ and $jy^2 z^2 i$ or $\beta y^2 r^2 i$ and $jz^2 x^2 i$. The second term in Eq.(1) is a "magnetic edd" for the orbital pseudospin, i.e. the orbital edd. Due to the relation $I_i^x + I_i^y + I_i^z = 0$, the orbital edd favors a peculiar orbital polarization and suppresses the orbital quantum fustration. However, if the spin correlations $h_i s_j i$ are identical along the x; y and z-directions, such as in the ferrom agnetic (FM) or the N cel antiferrom agnetic (G-type AFM) ordered structure, the orbital edd vanishes. Then the third spin-orbital interaction, which are equal along the x, the y and the zdirections, together with the fourth term leads to the strong quantum uctuations and results in an orbital disordered ground state⁹. Fortunately, the conventional JT instability lowers the cubic symmetry to the tetragonal crystalline edd, $f_{x}^2 = E_z \sum_{j=1}^{p} \frac{z}{j}$, is an additional orbital edd to break the symmetry of orbital space, and favors a peculiar orbital conguration. Thus the full Ham iltonian including the crystalline

eld term is read:

$$\hat{\mathbf{H}} = \hat{\mathbf{H}}_{SE} + \hat{\mathbf{H}}_{z}$$
(2.2)

Wewill discuss the cooperative JT e ect on the 00 in the Sect.V.

It is still a di cult task to treat the spin and orbital correlations and uctuations, and to nd the GS of Eq.(2) with high accuracy. To study the GS properties of these TMO systems,

we recently developed the cluster self-consistent eld (cluster-SCF) approach to study the 00 properties and the evolution of GS properties with interaction parameters in $V_2O_3^{-16}$. This approach combines the exact diagonalization and the self-consistent eld techniques, the main idea is brie y addressed as follows: rstly, choose a proper cluster, usually the unit cell of the TMO compound. Secondly, divide the interactions in Eq.(2) into two types: the internal bond interactions, H $_{\rm ij}$, between the sites R $_{\rm i}$ and R $_{\rm j}$ in the cluster, and the external bond interactions, H_{i1}^{0} , between the environment site R_1 and the site R_i in the cluster. The periodic condition enforces the electronic states at the environm ental site R₁ to be identical to the corresponding atom inside the cluster. A fter diagonalizing the internal interaction H $_{\rm ij}$ of the cluster, the interactions of the environm ent site R $_{\rm l}$ in H $_{\rm il}^{^{\rm O}}$ acting on the cluster are obtained as a initial value of the self-consistent eld (SCF): $h = T r_1 (I H_{i1}^{\circ})$, here I I is the reduced density matrix of the bond hili after tracing over all of the other sites in the cluster. Thirdly, diagonalize the cluster Ham iltonian H_{ij} in the presence of the SCF h_i^0 . Iteration is then perform ed until the orbital correlation functions and the SCF h_i° converge. The GS properties of the system and the e ective eld of the surrounding atom s applied on the inside atom s of the cluster are thus obtained. One of the advantages of the present approach is that the short-range correlation of the spins and the orbits, which is neglected in the conventional self-consistent m ean- eld m ethod, is taken into account.

To check the validity and convergence of the cluster-SCF approach, we apply it on the sim ple spin-1/2 AFM Heisenberg model. The Ham iltonian is read:

$$H = J \overset{X}{\underset{\text{hiji}}{}} \mathbf{s}_{i} \quad \mathbf{s}_{j} \tag{2.3}$$

where s_i is the operator for the i th spin and J > 0. In our numerical calculation code, the convergence of the GS energy is considered as the truncation condition of iterations, when the relative error of the GS energy between two iterations is within 10⁸, the GS energy is converged. The net nearest-neighbor spin correlation function $S(s_i;s_j) = hs_i$ si hs_i in hs_i and the spin polarization hs_z i are used cooperatively to determ ine the magnetic structure. We ind $S(s_i;s_j) = 0.1115$ along the three axes, and the spin polarizations of lattice clearly falls into two distinct kinds: hs_z i = 0.4683, and hs_z i= 0.4683. Obviously the GS is the N eel AFM structure, and the averaged spin deviation of the z component from 1/2 at each site is 0.0317, sm aller than Anderson's zero-point uctuation result 0.078¹⁷⁾. This di erence is attributed to the lack of the long-range quantum uctuation of the spins in our approach,

the present cluster-SCF approach includes only the short-range quantum uctuations. This result clearly con med the e ciency and validity of our approach.

III. ORBITAL TRANSITION INDUCED METAL-INSULATOR TRANSITION

In this section we rst utilize the cluster-SCF m ethod to nd the m agnetic and orbitalGS of Eq.(2), then explore the evolutions of the ordered orbital parameter and the energy gap of single-particle excitation spectra with increasing temperature in the strong correlation limit.

A. M agnetic and orbital structures in ground state

In many three-dimensional TMO the magnetic structure s are not dicult to determine by the neutron scattering and other experimental techniques, in the following in accordance with the spin conguration in the experiments, we treat the large local spins as semiclassical to save computation time, and focus on the orbital uctuation and the orbital GS for various magnetic orders. To determine the most stable magnetic and orbital GS structure of Eq.(2), we choose a cubic 8-site cluster. In the cluster, each site has three internal bonds and three external bonds. The total energy of the cluster as a function of the ratio $U=J_H$ for various



FIG.1: Dependence of the total energy on the ratio $U = J_H$ for di erent m agnetic structures. CO and GO denote the C-type and N eel antiferro-orbital ordered structures, respectively. Theoretical parameters: $J_H = 0.9eV$ and t = 0.1eV, $E_z = 5m eV$.



FIG. 2: Dependence of GS energy on the ratio $U=J_H$ in the classical approximation. A-AFO denotes the A-type antiferro-orbital ordered structure. Theoretical parameters are the same to Fig.1

m agnetic structures is shown in Fig.1. It is found that for sm all $U=J_H$, the GS is FM, which agrees with the mean-eld results of R oth¹⁸ and C yrot and Lyon-Caen's ¹⁹; while the GS is A -type AFM (A-AFM) for large $U=J_H$, i.e. AFM coupling along the c-axis and FM couplings in the ab-plane. In contrast, the classical approximation, which treats both the spin and the orbital operators as classical, shows that the GS is A-type AFM structure (A-AFM) over very wide $U=J_H$ range, as seen in Fig.2. This classical result is in agreement with K ugeland K hom skii's result ⁶⁾. As we will show later, after taking into account the quantum elect, the orbital occupation and polarization are slightly dimentified into account the classical results.

To nd the di erent stable magnetic structure sand the corresponding orbital congurations in di erent $U=_{H}J$ range, we take the net orbital-orbital correlation function, $C_{ij}=h_{i}$ fi h_i h_i, together with the orbitalization h_i to determ ine the orbital GS. In the FM phase, the Ising-like orbital-orbital interactions, $I_{i}^{1}I_{j_{i}}^{1}$, which are identical for l=x;y and z, as we analyzed in Sec.II, favors the orbital liquid GS. The tetragonal crystalline eld suppresses the quantum uctuations, drives the electrons into the $\beta^{2}z$ $r^{2}i$ orbit in $E_{z} < 0$, and stabilizes the GS as G-type antiferro-orbital (AFO) ordering, which is most favorable of the the anisotropic distribution of the electron clouds. This agrees with the empirical G oodenough-K anam ori rules ²⁰⁾. O ur num erical results further show that all of the orbital correlations, S_{ij} along the x, y and z-directions, are AFO, thus each site is AFO polarized with respect to its nearest-neighbor sites. One nds that the orbital occupations in the two sublattices are the combinations of jli and jli: $p_{\overline{21}jli} + p_{\overline{19}jli} = p_{\overline{40}}$, and $p_{\overline{21}jli} = p_{\overline{40}}$, for $U = J_H = 4.0$ and $E_z = 5m \text{ eV}$.

W ith the increasing of $U = J_H$, the electronic superexchange interaction becomes small, in comparison with the crystalline eld splitting, and more and more electrons occupy the j_x^2 y²i orbit. The FM phase becomes unstable and transits to the AFM GS at $(U=J_H)_c=4.1$. At $U=J_H=6.0$, the orbital occupations in the two sublattices are approximately p=3 jli + j2i = 2 and p=3 jli - j2i = 2, as shown in Fig.3. The single-bond coupling energy, which is calculated



FIG. 3: Single-bond spin coupling (SC) strength (3a) and orbital coupling (OC) energy (3b) as the function of $U=J_H$ for FM and A-AFM structures. $F_{x(y;z)}$ and $A_{x(y;z)}$ denote the x (y;z) bonds in the FM and the A-AFM structures, respectively.

for speci c spin con guration via $f_{1j}^{e} = T r_{s} (_{ij}H_{ij})$, consists of the orbital-dependent spin coupling energy and the pure orbital coupling energy. It is found in Fig.3a and Fig.3b that for sm all $U=J_{H}$, the FM structure is the most stable, and the quantum uctuation of spins is sm all; On the contrary, the A-AFM structure is the most stable for large $U=J_{H}$, addressing the GS orbital con guration in typical OO compound K C uF₃. In the following we focus the sm all U/J_{H} case. M ore detail results for large $U=J_{H}$ and the e ect of crystalline eld splitting on OO compound K C uF₃ will be presented in a further paper.

The orbital phase transitions with the variation of the Coulomb interaction are typical quantum phase transitions. We do not that the concurrence of two nearest-neighbor pseu-

dospins critically changes at the quantum transition point, detail result about how the entanglem ent of the orbital states evolves with the quantum phase transition will be published in the future. On the other hand, if we freeze the orbital conguration as the G-AFO ordered phase and to search the most stable spin conguration, we do not that the magnetic structure transition from FM to A-AFM also occurs at the same critical value $(U=J_H)_c=4.1$, congrig the validity of the orbital GS.

B. Tem perature dependence of orbital order param eter

A fier determ ining the orbital GS, we explore the in uence of the thermal uctuations on the spin and orbital order parameters. At nite temperature T, thermal uctuations exciting spin waves and orbital waves weaken both the orbital and the spin orderings, and destroy the magnetic order at the C urie temperature T_c and the 00 at the orbital critical temperature T₀₀. Since the spin order interplays with the 00, the reduction of spontaneous magnetization with increasing temperature also softens the orbital interaction, and vice versa. In the following we present the temperature dependence of the magnetic order and the 00 parameters in small U=J_H range (U=J_H < 4:1) in the conventional mean-eld approximation. In the FM and G-AFO phase, the mean-eld Ham iltonian is approximated as:

$$H_{MF} = \int_{A(B)}^{Z} J_{A(B)}^{z} + J_{A(B)}^{x} + J_{A(B)}^{x} + J_{s}s_{i}^{z}$$
(3.1)

where the coe cients $J_{A(B)}^{z}$, $J_{A(B)^{\times}}$ and J_{s} depend on the magnetic order and the 00 parameters, for example:

$$J_{s} = 3J_{1}hs^{z}i + 3=2J_{3}hs^{z}i(h_{A}^{z}ih_{B}^{z}i + h_{A}^{x}ih_{B}^{x}i)$$
(3.2)

etc. In the FM and G-AFO phase, the therm all averages of the spontaneous magnetization and the orbital polarization, i.e. the orbitalization, satisfy the following self-consistent equations:

$$hs_{a}^{z}i = Trfs_{a}^{z}exp (J_{sa}s_{a}^{z})g=Z_{a}^{s}$$

$$D E$$
(3.3)

where $= 1 = k_B T$. A lso, the self-consistent equations for the A-AFM and G-AFO phase at large $U = J_H$ can be obtained, but are more complicated. The tem perature dependence of the spin and 00 parameters for the system with small $U = J_H$ is shown in Fig.4.

At low tem perature, the magnetization and the two components of the orbitalization are nearly saturated. At lifting tem perature $T > T_c = 2$, the magnetization decreases considerably, while the orbitalization h~i almost does not change. With the tem perature approaching T_c , the magnetization rapidly falls to zero, and the magnetic transition is obviously the rst order, which originates from the strong anisotropy of the spin-orbit coupling, in agreement with T.M.Rice's argument based the Landau phenomenal theory for multiple parameter orders ²²⁾ and our renormalization group analysis to the critical indexes of the spin-orbital interaction models ²³⁾. Meanwhile the 00 parameter steeply diminishes a fraction at T_c , as observed in Fig.4. With further increasing in temperature, the 00 parameter gradually decreases and nally vanishes at T_{00} , with the characters of the second-order phase transition.

Due to the existence of orbital-orbital interaction in Hamiltonian (1), the long-range orbital correlation still exists after the magnetic order disappears. Therefore the orbital order-disorder transition temperature $T_{0\,0}$ is higher than the magnetic transition temperature T_c , as observed in Fig.4. It is worthwhile noticing that the orbitalization components $h^{z}i$ and $h^{x}i$ display considerable discontinuity at the Curie temperature T_c , which indicates the strong correlation between the spin and the orbital degrees of freedom. The falling fraction of the orbitalization near T_c is about 12% with respect to the saturated magnitude. The ab initio electronic structure calculations based on the local density approxim ation with



FIG. 4: Tem perature dependence of the magnetization s_z , the orbital polarizations $_z$ and $_x$. Theoretical parameters: U = 3:6eV, $J_H = 0.9eV$, t = 0:1eV.

correlation correction (LDA+U) have shown that in $KCuF_3$ the variation of the orbitaliza-

tion from the low-temperature AFM phase to the high-temperature paramagnetic phase is small, about 5% to 10% ²⁴⁾. Experiments, however, showed the variation of the orbitalization is about 50% or even 100% in KCuF₃ ²² and in V₂O₃ ²⁵. This discrepancy may arise from two reasons: the stone is that the paramagnetic phase calculated by the LDA+U approach at zero temperature neglects the change of the entropy due to the variation of the spin and orbital congurations; the second one is that in the LDA+U approach and the present work the long-range orbital uctuations are not taken into account.

C. Energy gap of single-particle spectra

In this subsection we study how the gap of single-particle energy spectra of the E_g electrons depends on the evolution of the 00 parameter. In the 00 phase, the long-range orbital order breaks the symmetry of the orbital space, and opens an insulating gap in single-particle excitation spectra of the TMO, forming an orbital insulator. Such an insulator di ers from the single-band M ott-H ubbard insulators in many aspects. One of the outstanding characters is that the insulating gap strongly depends on the 00 parameter, hence closely on the temperature. In the TMO with quarter lling, the tight-bonding spectrum of an E_g electron reads:

$$H_{t} = t \begin{pmatrix} X & h & p_{-} & i \\ d_{11}^{y} d_{11} & 3 & d_{11}^{y} d_{12} + d_{12}^{y} d_{11} + 3 d_{12}^{y} d_{12} \\ & & X \\ & X \\ & & X \\ & & + 4t & (d_{11}^{y} d_{11} + h x;) \\ & & & & hi; ii_{z} \end{pmatrix}$$
(3.5)

where d_i^y creates a 3d electron at site i with orbital state ; and denote the signs of the hopping integrals between two nearest-neighbor sites along the x and y direction, respectively. We ignore the spin index in the present FM GS.

Strong on-site C oulom b interaction U is the main character in these ordered TM O, that U >> t prohibits the E_g electrons from double occupation at the same site, thus the single occupation constraint is applied on the E_g orbits. In the lim it of large C oulom b interaction, the constraint of no double occupancy at site R_i is enforced by introducing auxiliary ferm ions $^{26)}$, f_i^y , and bosons, b_i ; here f_i^y creates a slaved ferm ion (electron) at site R_i with orbital state , and b_i^y creates a boson (hole) at site R_i , thus $d_i^y = f_i^y$ b_i, and the single occupation condition is: $P_i^y = f_i^y = 1$. In the FM and G-AFO ordered phase, the electrice

low -energy H am iltonian becom es:

$$H_{eff} = X \begin{bmatrix} \prod_{k}^{11} f_{k1}^{y} f_{k1} + \prod_{k}^{22} f_{k2}^{y} f_{k2} + \prod_{k}^{12} (f_{k1}^{y} f_{k2}) \\ + f_{k2}^{y} f_{k1} + J_{1}^{y} (f_{k+Q}^{y} f_{k2} + f_{k+Q}^{y} f_{k1})] \\ + (f_{k1}^{y} f_{k1} + f_{k2}^{y} f_{k2} + b^{2} - 1) \end{bmatrix}$$
(3.6)

here Q = (;;), corresponding to the G-AFO order. The average of the boson occupation is approximated as a c-number: $< b_1^y b_1 > = x$. The dispersion functions are: ${}_k^{11} = 4xt(\cos k_x + \cos k_y + 4\cos k_z) + 3 J_3 hs^z i^2 + J_4$ (h ^zi + E_z=2), ${}_k^{12} = 4^p \bar{3}xt(\cos k_x + \cos k_y)$, and ${}_k^{22} = 12xt(\cos k_x + \cos k_y) + 3 (J_3 hs^z i^2 + J_4)$ (h ^zi + E_z=2). And the parameter $J_1^r = 3 J_3 hs^z i^2 + J_4$ h ^xi. In the saddle-point approximation, the constraint constant and the boson occupation are:

$$= \frac{1}{N} \sum_{\substack{ij \\ hi; ji \\ 0}}^{X} t_{ij} \int_{i}^{0} f_{i}^{Y} f_{j} + H C$$
(3.7)

$$x = 1 \frac{1}{N} \frac{1}{N} \int_{i_{1}}^{N} f_{i_{1}} f_{i_{1}} + f_{i_{2}}^{y} f_{i_{2}}$$
(3.8)

respectively. Physically shifts the energy level of the Ferm i quasiparticles, and x gives rise to the hole concentration upon doping. In the compounds with quarter-lling, x ! 0. The single-quasiparticle energy spectra E_k have four branches and strongly depend on the 00 parameter. For the G-AFO ordered TMO the lower two subbands are lled, since each m agnetic and orbital unit cell contains two electrons at quarter-lling, the minimum of the empty subband separates from the maximum of the lled subbands by a gap . This result considerably di ers from K ilian and K haliullian's gapless charge excitation¹⁵⁾; in fact, in their study the modulation of the long-range 00 on the motion of the electrons was not taken into account.

The thermal uctuation weakens the OO parameter, hence softens the single-particle excitation spectra. The T-dependence of the energy gap of the single-particle spectra is shown in Fig.5. At low T, the strong Coulomb interaction of the 3d electrons, the large spatial anisotropy of 3d orbits and the crystalline eld splitting cooperatively lift the orbital degeneracy, and favor the ordered orbital phase. The broken of the orbital space symmetry leads to that an electron must cost at least in energy to hop to the nearest-neighbor site. Therefore the threshold gives rise to the insulating gap of the TMO as an orbital



FIG. 5: Tem perature dependence of the energy gap of the single-particle spectra in the ferrom agnetic and G-type antiferro-orbital ordered phase. = 0:1eV, and other parameters are the same to Fig.4.

insulator. This energy gap manifests in the optical excitation and transport, and di ers from the energy gap of the orbital wave excitation. Increasing tem perature gradually destroys the long-range 00, and leads to the decrease of the gap of the separated subbands. W ith the further increasing of tem perature to $T = T_{00}$, the therm all uctuations become so strong that the long-range 00 and the 00 parameter vanish. In this situation, the two lower subbands m erge together with the two higher subbands, the insulating gap disappears, see F ig 5, indicating the occurrence of M IT in TM 0. Thus the energy gap of the orbital insulator crucially depends on the 00 parameter, hence the tem perature.

The temperature dependence of the insulating gap (T) turns out to be similar to that of the 00 parameter, steeply diminishes a fraction at the Curie temperature T_c and com – pletely disappears at T_{00} , see Fig.4 and Fig.5. Therefore, the temperature driven M IT in TM 0 is essentially induced by the orbital order-disorder transition. Our num erical results demonstrate the signi cant discrepancy between the optical and transport gap (T) and the M IT critical temperature T_M . For the present system in Fig.5, the gap of the energy spectra, usually relected in optical and transport experiments, is = 0.5 eV; while the M IT critical temperature $T_M = T_{00}$ 270K = 0.023, which accounts for the considerable discrepancy between and T_M in many orbital compounds. IV. TEMPERATURE-DEPENDENT RESONANT X-RAY SCATTERING IN-TENSITIES

Strong interplay between spin and orbital degrees of freedom also manifests In the optical excitation of orbital insulating TMO. Recently it was proposed to utilizing the RXS technique to measure the OO phase by Murakamietal. ²⁸ for manganites and Fabrizio et al. ²⁹ for V₂O₃. The 1s 3d K-edge RXS peak intensity is a useful signal to probe the OO phase and the orbital order-disorder phase transitions ^{11,27}. The polarization and azim uthal dependences of the RXS intensities provide the hidden information of the underlying OO parameters ^{27 30}, and unveil the interplay between spins and orbits. A lthough the signal enhancement of the quadrupole 1s 3d scattering (E₂) is less than that of the electric dipole 1s 4p scattering (E₁), the observed E₂ spectral line shape as a function of energy is more easy to be identieed than the quite complicated line shapes associated with E₁ process ^{11,28,29}. In what follows we present the E₂ RXS intensity and its evolution with temperature based on the OO phase obtained in the preceding section.

In the FM and G-AFO phase, the ordered 3d orbits in the sublattices consist of two di erent orbital basis: $j_1i = _1jli + _2jli$ and $j_2i = _1jli __2jli$, here the coe cients __1; __2 are the functions of the interaction parameters. There exist two kinds of re ections: the fundamental rection at (hkl) = (n_k n_y n_z) and the orbital superlattice re ection at (hkl) = $n_x + \frac{1}{2}; n_y + \frac{1}{2}; n_z + \frac{1}{2}$. At the lattice symmetry-forbidden direction in which (hkl) are allodd, the orbital structure factor is written as:

$$F_{hkl} = 8^{p} \overline{3}f(; k_{zds}; c; l)^{p} \overline{n_{k}n_{k}}h_{x}i[zk_{z}]$$

$$\int_{x}^{0} k_{x}^{0} \int_{y}^{0} k_{y}^{0} + (zk_{x} yk_{y})\int_{z}^{0} k_{z}^{0}] \qquad (4.1)$$

where the function f (; $\mathfrak{p}_{\text{zds}}$; c; !) is the coe cient depending on the lifetime of the intermediate states, , the radial matrix element $\mathfrak{p}_{\text{zds}}$, the velocity of photon c and the incoming photon frequency !; n $_{(^0),k(k^0)}$ is the density of the incoming (outgoing) beam of photons with polarization ~ $^{-0}$ and wavevector \tilde{k} \tilde{k}^0 . When the incoming beam is perfect -polarized, the orbital structure factor for unrotated ($^{-0}$) channel is:

$$F_{0} = \frac{n_{k_{k}} n_{k_{0}}}{3} f(; p_{jds}; c; !) h_{x} i [3 \cos^{2} (\sin^{2} 2')]$$

$$\sin 4') + 8 \sin^{2} (\sin^{2} ' \sin 2')] \qquad (4.2)$$

where and ' are the Bragg and the azim uthal angles, respectively. The azim uthal-angle and the tem perature dependences of the RXS intensities at a selected azim uth angle of the OO superlattice Bragg re ection (111) are shown in Fig.6. A steep decrease of the RXS



FIG. 6: Tem perature (Fig.a) and azim uthal dependence of RXS intensities in the ferrom agnetic and G-type orbital ordered phase in (111) direction for the unrotated (0) (Fig.b) and the rotated (0) (Fig.c) channels.

intensities at T_c is observed in Fig.6. This discontinuous decrease is associated with the lost of magnetic order, which diminishes a fraction of orbital interaction. Such a discontinuous decrease is widely observed in the RXS experiments in manganites, KCuF₃ and YVO₃, a signi cant evidence of the strong spin-orbit coupling. The K-edge RXS peaks disappear completely at the 00T or MIT critical point. Therefore the RXS intensity could be a probe to the critical point of the MIT in orbital insulators.

V. REMARKSAND SUMMARY

In the preceding sections we focus on the system with FM and G-AFO structure. For large $U=J_H$, the GS of the system is the A-AFM and G-AFO (C-AFO) ordered phase, as determined by the cluster-SCF approach. We indisid an orbital ordered TMO also opens

an insulating gap in the single-particle energy spectra, and the energy gap exhibits sin ilar dependences on the 00 parameter and the temperature to those in the present paper. The dependence of the RXS intensity on temperature is also similar to the preceding result qualitatively, though the peak positions of the RXS intensities slightly shift in comparison with the present structure. Therefore dierent ordered orbital insulators share many common characteristics, and are signic cantly dierent from the conventional single-band M ott-H ubbard insulators ^{1,31}.

M any cubic sym m etric TM O with orbital degeneracy are inherently unstable, the orbital degeneracy is usually lifted by lowering the crystal sym m etry through the JT distortions in LaM nO₃ ³² and YVO₃ ³³, or other lattice distortion m odes in V₂O₃ ¹⁶. As far as the JT phonon-m ediated orbital coupling is considered, an additional orbital-orbital interaction is introduced ⁹:

$$\hat{H}_{JT} = \sum_{\substack{\text{hij},i\\\text{hij},i}}^{X^{Y/2}} \frac{2g^2}{3K} I_i^1 I_{j_1}^1$$
(5.1)

where g is the electron-phonon coupling constant, and K the restoring coe cient. For typical TMO in which JT e ect plays a role, the parameters g 1.2 eV, and K 10.0 eV. In this situation, the orbital correlation arises from both the Coulomb interaction and the JT e ect, thus the orbital GS is a combination of the pure electronic spin-orbital superexchange interaction and the crystalline eld splitting described by Eq.(2) and the JT orbital interaction by Eq.(14). U tilizing the cluster-SCF m ethod, we nd that the m ost stable GS m agnetic structure in this case is still FM and G-AFO ordering with a slight m odi cation on the orbital occupation for sm all U=J_H; and for large U=J_H the GS is A-AFM and G-AFO ordering. Such system also exhibits m ost of characters of orbital insulators.

An obvious fact is that m any 00 insulators do not exhibit M IT when the long-range 00 disappears at high tem perature, such as in LaM nO₃³⁴⁾ and YVO₃³³⁾, except for V₂O₃. The essential reason is that these TM 0 are not simple orbital insulators, there also exists strong dynam ic electron-phonon coupling, i.e., the dynam ic JT e ect, even if the static cooperative JT distortion disappears at high tem perature. In these com pounds, num erous dynam ic JT phonons drag the m otion of 3d electrons, and localize the 3d electrons as the incoherent polarons. The transport of the 3d electrons dragged by num erous dynam ic phonons is of insulated polaronic character. Therefore these TM 0 are still insulators at high tem perature. This addressed why $T_M \notin T_{00}$ in some compounds.

An important result from the preceding study is that the crystalline eld splitting E_z plays crucial role for the stability of the OO GS.A pure spin-orbital interaction can not solely determ ine the magnetic and orbital GS, since the quantum uctuation is large and the spin-orbital interacting system is still highly degenerate. The crystalline eld splitting E_z may suppress the quantum uctuation and drive the system into an stable GS.Sim ilar result was also obtained by Fang and Nagaosa in the orbital compound YVO₃ in a recent paper ³⁵.

In sum mary, in an orbital-degenerate spin-orbital interacting system, besides the orbital wave gap, an energy gap of the electronic excitation is opened as the orbital order develops, and disappears with the vanishing of the orbital order driven by the therm al uctuations. The clear dependence of the insulating gap on the orbital order parameters shows that such TMO possesses the orbital insulator characters, and from which one could interpret the considerable discrepancy between the energy gap in the optical and transport experiments and the MIT critical temperature. The RXS intensity also exhibits the close interplay between spin and orbital orders. We expect more interesting properties of orbital insulator, such as the critical index near the transition point of the MIT, will be uncovered in the further studies.

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17

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